芯伯乐®
XINBOLE

Product Specification

XBLW SN74HC373

Octal D-type transparent latch; 3-state

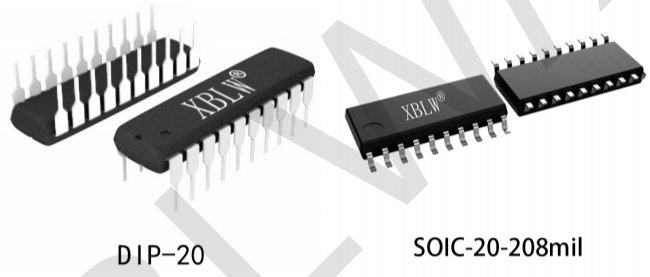
WEB | www.xinboleic.com

Description

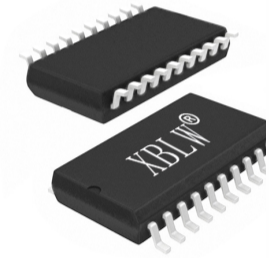
The SN74HC373 is a octal D-type transparent latch with 3-state outputs. The device features latch enable (LE) and output enable ($\overline{OE}$) inputs. When LE is HIGH, data at the inputs enter the latches. In this condition the latches are transparent, a latch output will change each time its corresponding D -input changes. When LE is LOW the latches store the information that was present at the inputs a set -up time preceding the HIGH-to-LOW transition of LE. A HIGH on $\overline{OE}$ causes the outputs to assume a high-impedance OFF-state. Operation of the $\overline{OE}$ input does not affect the state of the latches. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

Features

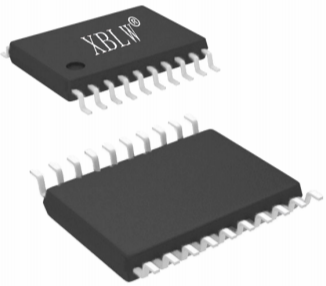
- 3-state non-inverting outputs for bus-oriented applications
- Common 3-state output enable input
- Specified from -40°C to +125°C
- Packaging information: DIP-20/SOP-20/TSSOP-20/SOIC-20-208mil



DIP–20 SOIC-20-208mil



SOP–20



TSSOP-20

Ordering Information

Product Model	Package Type	Marking	Packing	Packing Qty
XBLW SN74HC373N	DIP-20	74HC373N	Tube	720Pcs/Box
XBLW SN74HC373DTR	SOP-20	74HC373	Tape	2000Pcs/Reel
XBLW SN74HC373TDTR	TSSOP-20	74HC373	Tape	2000Pcs/Reel
XBLW SN74HC373NSDTR	SOIC-20-208mil	74HC373	Tape	2000Pcs/Reel

Block Diagram

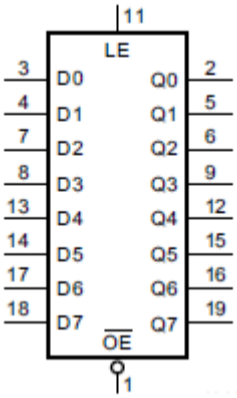


Figure 1. Logic symbol

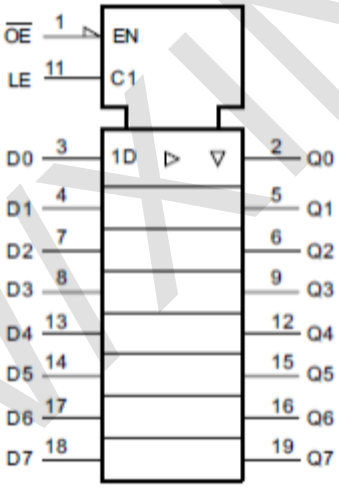


Figure 2. IEC logic symbol

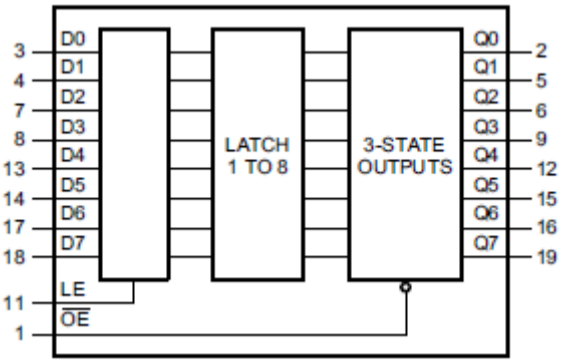


Figure 3. Functional diagram

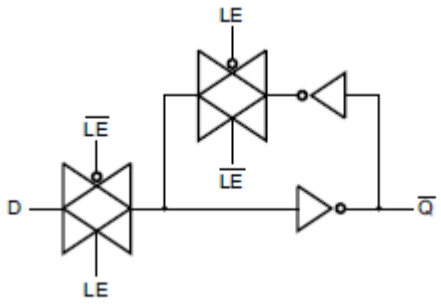


Figure 4. Logic diagram (one latch)

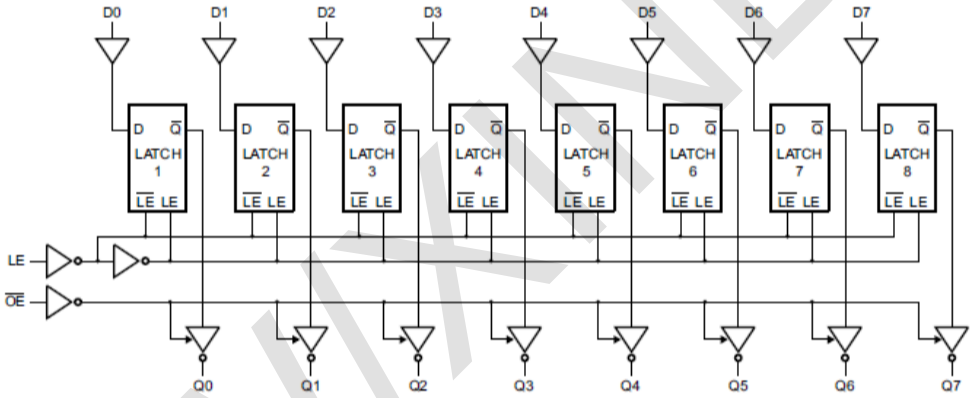
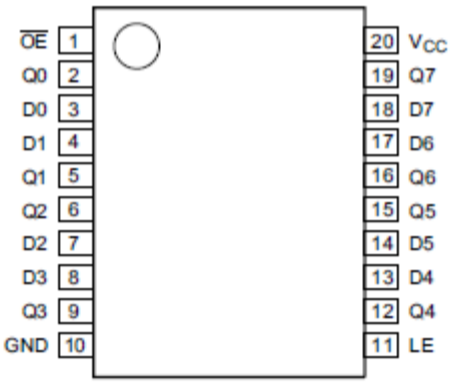


Figure 5. Logic diagram

Pin Configurations



Pin Description

Pin No.	Pin Name	Description
1	$\overline{OE}$	3-state output enable input (active LOW)
2	Q0	3-state latch output
3	D0	data input
4	D1	data input
5	Q1	3-state latch output
6	Q2	3-state latch output
7	D2	data input
8	D3	data input
9	Q3	3-state latch output
10	GND	ground (0V)
11	LE	latch enable input (active HIGH)
12	Q4	3-state latch output
13	D4	data input
14	D5	data input
15	Q5	3-state latch output
16	Q6	3-state latch output
17	D6	data input
18	D7	data input
19	Q7	3-state latch output
20	V_{CC}	supply voltage

Function Table

Operating mode	Control		Input	Internal latches	Output
	$\overline{OE}$	LE	Dn		Qn
Enable and read register (transparent mode)	L	H	L	L	L
			H	H	H
Latch and read register	L	L	l	L	L
			h	H	H
Latch register and disable outputs	H	X	X	X	Z

Note: H=HIGH voltage level; L=LOW voltage level; Z=high-impedance OFF-state; X=don't care;
h = HIGH voltage level one set-up time prior to the HIGH-to-LOW LE transition;
l = LOW voltage level one set-up time prior to the HIGH-to-LOW LE transition.

Electrical Parameter

Absolute Maximum Ratings

(Voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Max.	Unit
supply voltage	V_{CC}	-		-0.5	+7.0	V
input clamping current	I_{IK}	V_I < -0.5V or V_I > V_{CC}+0.5V		-	±20	mA
output clamping current	I_{OK}	V_O < -0.5V or V_O > V_{CC}+0.5V		-	±20	mA
output current	I_O	V_O= -0.5V to (V_{CC}+0.5V)		-	±35	mA
supply current	I_{CC}	-		-	+70	mA
ground current	I_{GND}	-		-70	-	mA
storage temperature	T_{stg}	-		-65	+150	°C
total power dissipation	P_{tot}	-		-	500	mW
Soldering temperature	T_L	10s	DIP	245		°C
			SOP/TSSOP	260		

Recommended Operating Conditions

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
supply voltage	V_{CC}	-	2.0	5.0	6.0	V
input voltage	V_I	-	0	-	V_{CC}	V
output voltage	V_O	-	0	-	V_{CC}	V
input transition rise and fall rate	Δt/ΔV	V_{CC}=2.0V	-	-	625	ns/V
		V_{CC}=4.5V	-	1.67	139	ns/V
		V_{CC}=6.0V	-	-	83	ns/V
ambient temperature	T_{amb}	-	-40	-	+125	°C

Electrical Characteristics

DC Characteristics 1

(T_{amb}=25°C, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
HIGH-level input voltage	V_{IH}	V_{CC}=2.0V		1.5	1.2	-	V
		V_{CC}=4.5V		3.15	2.4	-	V
		V_{CC}=6.0V		4.2	3.2	-	V
LOW-level input voltage	V_{IL}	V_{CC}=2.0V		-	0.8	0.5	V
		V_{CC}=4.5V		-	2.1	1.35	V
		V_{CC}=6.0V		-	2.8	1.8	V
HIGH-level output voltage	V_{OH}	V_I = V_{IH} or V_{IL}	I_O=-20uA; V_{CC}=2.0V	1.9	2.0	-	V
			I_O=-20uA; V_{CC}=4.5V	4.4	4.5	-	V
			I_O=-20uA; V_{CC}=6.0V	5.9	6.0	-	V
			I_O=-6.0mA; V_{CC}=4.5V	3.98	4.32	-	V
			I_O=-7.8mA; V_{CC}=6.0V	5.48	5.81	-	V
LOW-level output voltage	V_{OL}	V_I = V_{IH} or V_{IL}	I_O=20uA; V_{CC}=2.0V	-	0	0.1	V
			I_O=20uA; V_{CC}=4.5V	-	0	0.1	V
			I_O=20uA; V_{CC}=6.0V	-	0	0.1	V
			I_O=6.0mA; V_{CC}=4.5V	-	0.15	0.26	V
			I_O=7.8mA; V_{CC}=6.0V	-	0.16	0.26	V
input leakage current	I_I	V_I=V_{CC} or GND; V_{CC}=6.0V		-	-	±1.0	uA
OFF-state output current	I_{OZ}	V_I=V_{IH} orV_{IL}; V_{CC}=6.0V; V_O=V_{CC} or GND		-	-	±1.0	uA
supply current	I_{CC}	V_I=V_{CC} or GND; I_O=0A; V_{CC}=6.0V		-	-	8.0	uA
input capacitance	C_I	-		-	3.5	-	pF

DC Characteristics 2

(T_{amb}=-40°C to +85°C, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
HIGH-level input voltage	V_{IH}	V_{CC}=2.0V		1.5	-	-	V
		V_{CC}=4.5V		3.15	-	-	V
		V_{CC}=6.0V		4.2	-	-	V
LOW-level input voltage	V_{IL}	V_{CC}=2.0V		-	-	0.5	V
		V_{CC}=4.5V		-	-	1.35	V
		V_{CC}=6.0V		-	-	1.8	V
HIGH-level output voltage	V_{OH}	V_I = V_{IH} or V_{IL}	I_O=-20uA; V_{CC}=2.0V	1.9	-	-	V
			I_O=-20uA; V_{CC}=4.5V	4.4	-	-	V
			I_O=-20uA; V_{CC}=6.0V	5.9	-	-	V
			I_O=-6.0mA; V_{CC}=4.5V	3.84	-	-	V
			I_O=-7.8mA; V_{CC}=6.0V	5.34	-	-	V
LOW-level output voltage	V_{OL}	V_I = V_{IH} or V_{IL}	I_O=20uA; V_{CC}=2.0V	-	-	0.1	V
			I_O=20uA; V_{CC}=4.5V	-	-	0.1	V
			I_O=20uA; V_{CC}=6.0V	-	-	0.1	V
			I_O=6.0mA; V_{CC}=4.5V	-	-	0.33	V
			I_O=7.8mA; V_{CC}=6.0V	-	-	0.33	V
input leakage current	I_I	V_I=V_{CC} or GND; V_{CC}=6.0V		-	-	±1.0	uA
OFF-state output current	I_{OZ}	V_I=V_{IH} orV_{IL}; V_{CC}=6.0V; V_O=V_{CC} or GND		-	-	±5.0	uA
supply current	I_{CC}	V_I=V_{CC} or GND; I_O=0A; V_{CC}=6.0V		-	-	80	uA

Electrical Characteristics

DC Characteristics 3

(T_{amb}=-40℃ to +125℃, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
HIGH-level input voltage	V_{IH}	V_{CC}=2.0V		1.5	-	-	V
		V_{CC}=4.5V		3.15	-	-	V
		V_{CC}=6.0V		4.2	-	-	V
LOW-level input voltage	V_{IL}	V_{CC}=2.0V		-	-	0.5	V
		V_{CC}=4.5V		-	-	1.35	V
		V_{CC}=6.0V		-	-	1.8	V
HIGH-level output voltage	V_{OH}	V_I = V_{IH} or V_{IL}	I_O=-20uA; V_{CC}=2.0V	1.9	-	-	V
			I_O=-20uA; V_{CC}=4.5V	4.4	-	-	V
			I_O=-20uA; V_{CC}=6.0V	5.9	-	-	V
			I_O=-6.0mA; V_{CC}=4.5V	3.7	-	-	V
			I_O=-7.8mA; V_{CC}=6.0V	5.2	-	-	V
LOW-level output voltage	V_{OL}	V_I = V_{IH} or V_{IL}	I_O=20uA; V_{CC}=2.0V	-	-	0.1	V
			I_O=20uA; V_{CC}=4.5V	-	-	0.1	V
			I_O=20uA; V_{CC}=6.0V	-	-	0.1	V
			I_O=6.0mA; V_{CC}=4.5V	-	-	0.4	V
			I_O=7.8mA; V_{CC}=6.0V	-	-	0.4	V
input leakage current	I_I	V_I=V_{CC} or GND; V_{CC}=6.0V		-	-	±1.0	uA
OFF-state output current	I_{OZ}	V_I=V_{IH} orV_{IL}; V_{CC}=6.0V; V_O=V_{CC} or GND		-	-	±10	uA
supply current	I_{CC}	V_I=V_{CC} or GND; I_O=0A; V_{CC}=6.0V		-	-	160	uA

AC Characteristics 1

(T_{amb}=25°C, GND =0V, C_L=50pF, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
propagation delay	t_{pd}	Dn to Qn; see Figure 7	V_{CC}=2.0V	-	41	150	ns
			V_{CC}=4.5V	-	15	30	ns
			V_{CC}=5.0V; C_L=15pF	-	12	-	ns
			V_{CC}=6.0V	-	12	26	ns
		LE to Qn; see Figure 8	V_{CC}=2.0V	-	50	175	ns
			V_{CC}=4.5V	-	18	35	ns
			V_{CC}=5.0V; C_L=15pF	-	15	-	ns
			V_{CC}=6.0V	-	14	30	ns
$\overline{OE}$ to Qn enable time	t_{en}	see Figure 9	V_{CC}=2.0V	-	44	150	ns
			V_{CC}=4.5V	-	16	30	ns
			V_{CC}=6.0V	-	13	26	ns
$\overline{OE}$ to Qn disable time	t_{dis}	see Figure 9	V_{CC}=2.0V	-	47	150	ns
			V_{CC}=4.5V	-	17	30	ns
			V_{CC}=6.0V	-	14	26	ns
transition time	t_t	Qn; see Figure 7, 8	V_{CC}=2.0V	-	14	60	ns
			V_{CC}=4.5V	-	5	12	ns
			V_{CC}=6.0V	-	4	10	ns
pulse width	t_W	LE HIGH; see Figure 8	V_{CC}=2.0V	80	17	-	ns
			V_{CC}=4.5V	16	6	-	ns
			V_{CC}=6.0V	14	5	-	ns
set-up time	t_{su}	Dn to LE; see Figure 10	V_{CC}=2.0V	50	14	-	ns
			V_{CC}=4.5V	10	5	-	ns
			V_{CC}=6.0V	9	4	-	ns
hold time	t_h	Dn to LE; see Figure 10	V_{CC}=2.0V	+5	-8	-	ns
			V_{CC}=4.5V	+5	-3	-	ns
			V_{CC}=6.0V	+5	-2	-	ns
power dissipation capacitance	C_{PD}	per latch; V_I=GND to V_{CC}		-	45	-	pF

Note:
[1] t_{pd} is the same as t_{PLH} and t_{PHL}.
[2] t_{en} is the same as t_{PZL} and t_{PZH}.
[3] t_{dis} is the same as t_{PLZ} and t_{PHZ}.
[4] t_t is the same as t_{THL} and t_{TLH}.
[5] C_{PD} isused to determine the dynamic power dissipation (P_D in uW).
$P_D=C_{PD}\times V_{CC}^2\times f_i\times N+\Sigma(C_L\times V_{CC}^2\times f_o)$ where:
f_i=input frequency in MHz; f_o=output frequency in MHz; C_L=output load capacitance in pF;
V_{CC}=supply voltage in V;
N=number of inputs switching; $\Sigma(C_L\times V_{CC}^2\times f_o)$=sum of outputs.

AC Characteristics 2

(T_{amb}=-40°C to +85°C, GND= 0V, C_L= 50pF, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
propagation delay	t_{pd}	Dn to Qn; see Figure 7	V_{CC}=2.0V	-	-	190	ns
			V_{CC}=4.5V	-	-	38	ns
			V_{CC}=6.0V	-	-	33	ns
		LE to Qn; see Figure 8	V_{CC}=2.0V	-	-	220	ns
			V_{CC}=4.5V	-	-	44	ns
			V_{CC}=6.0V	-	-	37	ns
$\overline{OE}$ to Qn enable time	t_{en}	see Figure 9	V_{CC}=2.0V	-	-	190	ns
			V_{CC}=4.5V	-	-	38	ns
			V_{CC}=6.0V	-	-	33	ns
$\overline{OE}$ to Qn disable time	t_{dis}	see Figure 9	V_{CC}=2.0V	-	-	190	ns
			V_{CC}=4.5V	-	-	38	ns
			V_{CC}=6.0V	-	-	33	ns
transition time	t_t	Qn; see Figure 7, 8	V_{CC}=2.0V	-	-	75	ns
			V_{CC}=4.5V	-	-	15	ns
			V_{CC}=6.0V	-	-	13	ns
pulse width	t_W	LE HIGH; see Figure 8	V_{CC}=2.0V	100	-	-	ns
			V_{CC}=4.5V	20	-	-	ns
			V_{CC}=6.0V	17	-	-	ns
set-up time	t_{su}	Dn to LE; see Figure 10	V_{CC}=2.0V	65	-	-	ns
			V_{CC}=4.5V	13	-	-	ns
			V_{CC}=6.0V	11	-	-	ns
hold time	t_h	Dn to LE; see Figure 10	V_{CC}=2.0V	5	-	-	ns
			V_{CC}=4.5V	5	-	-	ns
			V_{CC}=6.0V	5	-	-	ns

Note:

[1] t_{pd} is the same as t_{PLH} and t_{PHL}.

[2] t_{en} is the same as t_{PZL} and t_{PZH}.

[3] t_{dis} is the same as t_{PLZ} and t_{PHZ}.

[4] t_t is the same as t_{THL} and t_{TLH}.

AC Characteristics 3

(T_{amb}=-40°C to +125°C, GND= 0V, C_L= 50pF, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
propagation delay	t_{pd}	Dn to Qn; see Figure 7	V_{CC}=2.0V	-	-	225	ns
			V_{CC}=4.5V	-	-	45	ns
			V_{CC}=6.0V	-	-	38	ns
		LE to Qn; see Figure 8	V_{CC}=2.0V	-	-	265	ns
			V_{CC}=4.5V	-	-	53	ns
			V_{CC}=6.0V	-	-	45	ns
$\overline{OE}$ to Qn enable time	t_{en}	see Figure 9	V_{CC}=2.0V	-	-	225	ns
			V_{CC}=4.5V	-	-	45	ns
			V_{CC}=6.0V	-	-	38	ns
$\overline{OE}$ to Qn disable time	t_{dis}	see Figure 9	V_{CC}=2.0V	-	-	225	ns
			V_{CC}=4.5V	-	-	45	ns
			V_{CC}=6.0V	-	-	38	ns
transition time	t_t	Qn; see Figure 7, 8	V_{CC}=2.0V	-	-	90	ns
			V_{CC}=4.5V	-	-	18	ns
			V_{CC}=6.0V	-	-	15	ns
pulse width	t_W	LE HIGH; see Figure 8	V_{CC}=2.0V	120	-	-	ns
			V_{CC}=4.5V	24	-	-	ns
			V_{CC}=6.0V	20	-	-	ns
set-up time	t_{su}	Dn to LE; see Figure 10	V_{CC}=2.0V	75	-	-	ns
			V_{CC}=4.5V	15	-	-	ns
			V_{CC}=6.0V	13	-	-	ns
hold time	t_h	Dn to LE; see Figure 10	V_{CC}=2.0V	5	-	-	ns
			V_{CC}=4.5V	5	-	-	ns
			V_{CC}=6.0V	5	-	-	ns

Note:

[1] t_{pd} is the same as t_{PLH} and t_{PHL}.

[2] t_{en} is the same as t_{PZL} and t_{PZH}.

[3] t_{dis} is the same as t_{PLZ} and t_{PHZ}.

[4] t_t is the same as t_{THL} and t_{TLH}.

Testing Circuit

AC Testing Circuit

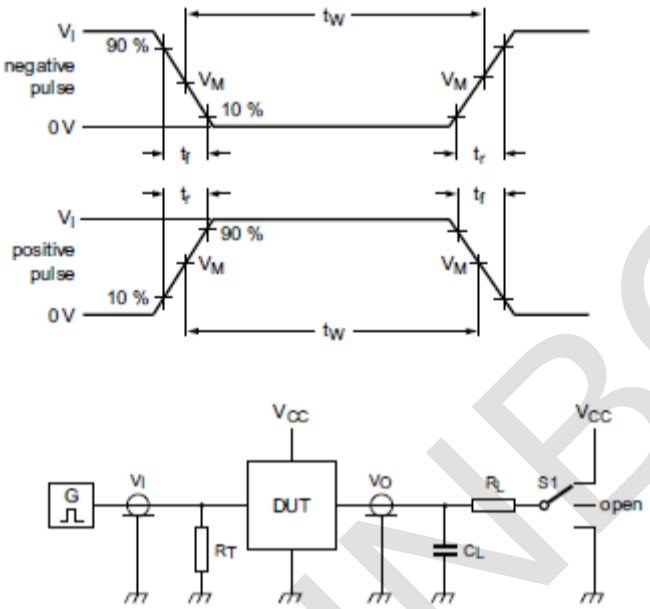


Figure 6. Test circuit for measuring switching times

Definitions for test circuit:

R_L=Load resistance.

C_L=Load capacitance including jig and probe capacitance.

R_T=Termination resistance should be equal to the output impedance Z_o of the pulse generator.

S1=Test selection switch.

AC Testing Waveforms

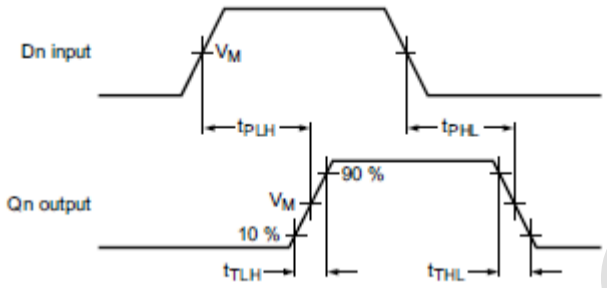


Figure 7. Propagation delay data input (Dn) to output (Qn) and output transition time

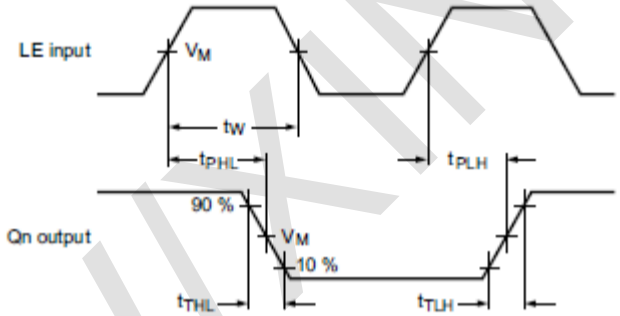


Figure 8. Pulse width latch enable input (LE), propagation delay latch enable input (LE) to output (Qn) and output transition time

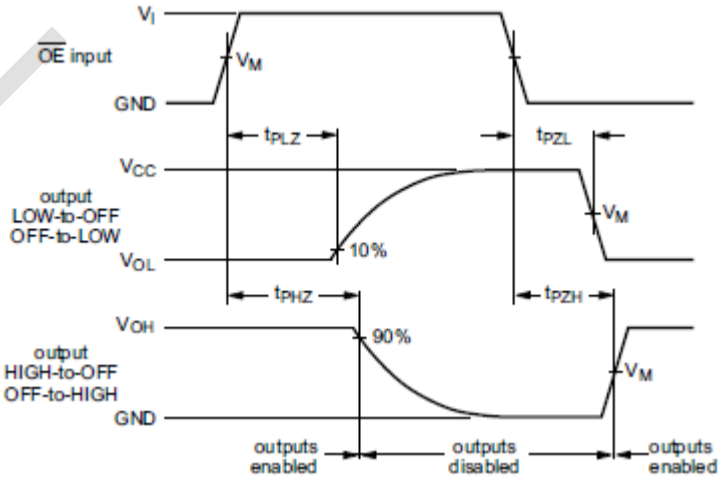


Figure 9. Enable and disable times

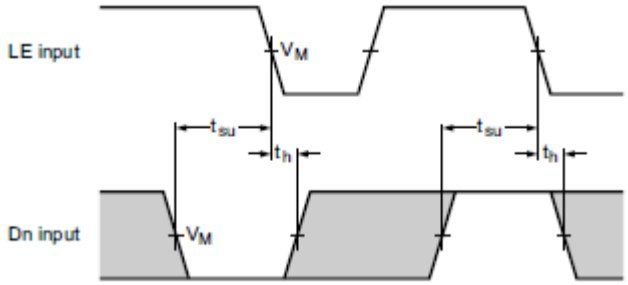


Figure 10. Set-up and hold times for data input (Dn) to latch input (LE)

Measurement Points

Type	Input	Output
	V_M	V_M
SN74HC373	$0.5\times V_{CC}$	$0.5\times V_{CC}$

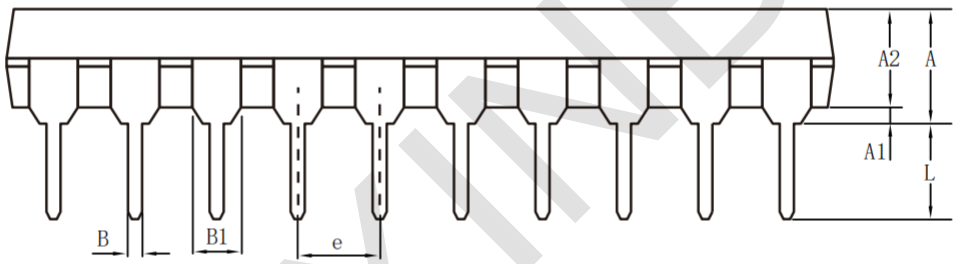
Test Data

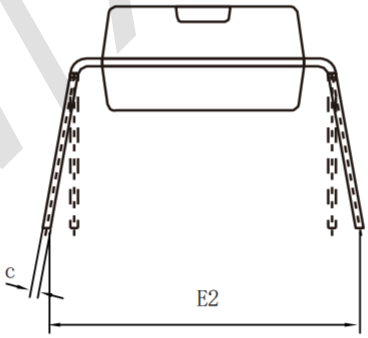
Type	Input		Load		S1 position		
	V_I	t_r ,t_f	C_L	R_L	t_{PHL}, t_{PLH}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ}
SN74HC373	V_{CC}	6ns	15pF, 50pF	1kΩ	open	GND	V_{CC}

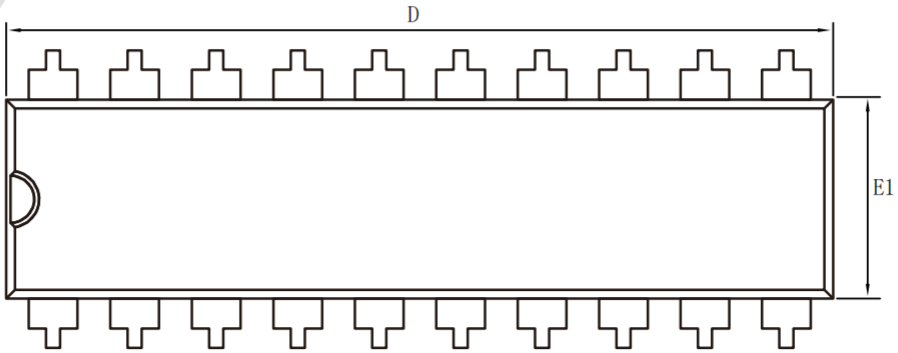
Package Information

· DIP-20

Size / Symbol	Dimensions In Millimeters		Size / Symbol	Dimensions In Inches	
	Min(mm)	Max(mm)		Min(in)	Max(in)
A	3.600	5.330	A	0.142	0.210
A1	0.510		A1	0.020	
A2	3.200	3.600	A2	0.126	0.142
B	0.360	0.530	B	0.014	0.021
B1	1.52(BSC)		B1	0.060(BSC)	
c	0.204	0.360	c	0.008	0.014
D	25.70	26.54	D	1.010	1.040
E1	6.200	6.750	E1	0.244	0.260
E2	7.620	9.300	E2	0.300	0.366
e	2.54(BSC)		e	0.100(BSC)	
L	3.000	3.600	L	0.118	0.142

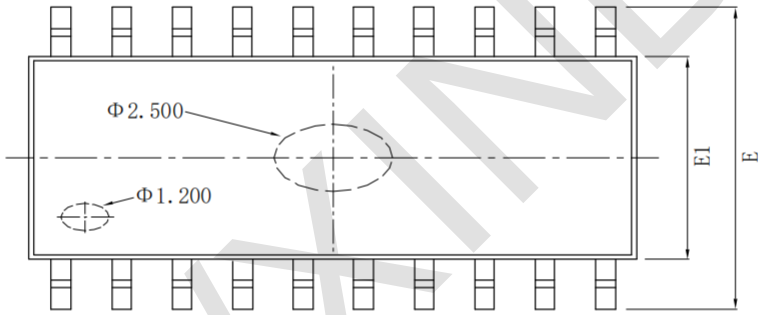


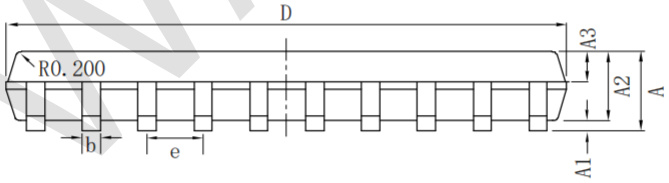


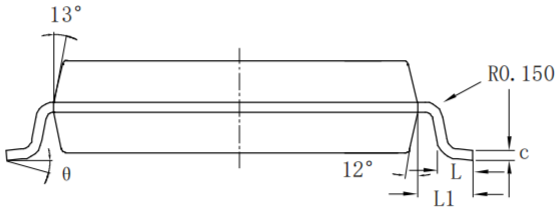


· SOIC-20-208mil

Size / Symbol	Dimensions In Millimeters		Size / Symbol	Dimensions In Inches	
	Min(mm)	Max(mm)		Min(in)	Max(in)
A		2.000	A		0.079
A1	0.050	0.250	A1	0.002	0.010
A2	1.650	1.850	A2	0.065	0.073
b	0.350	0.550	b	0.014	0.022
c	0.150	0.200	c	0.006	0.008
D	12.25	12.65	D	0.482	0.498
E	7.600	8.000	E	0.299	0.315
E1	5.100	5.500	E1	0.201	0.217
e	1.270		e	0.050	
L	0.550	0.950	L	0.022	0.037
L1	1.250		L1	0.049	
θ	0°	8°	θ	0°	8°

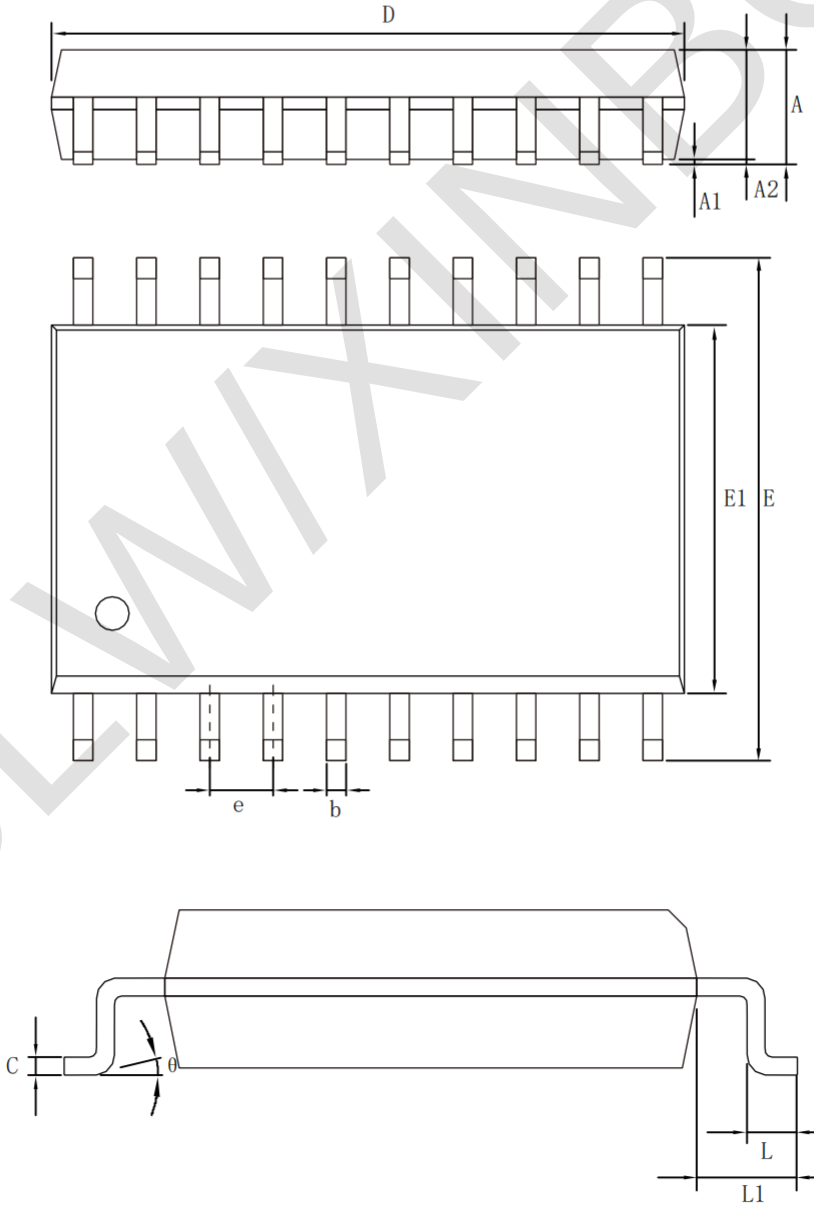






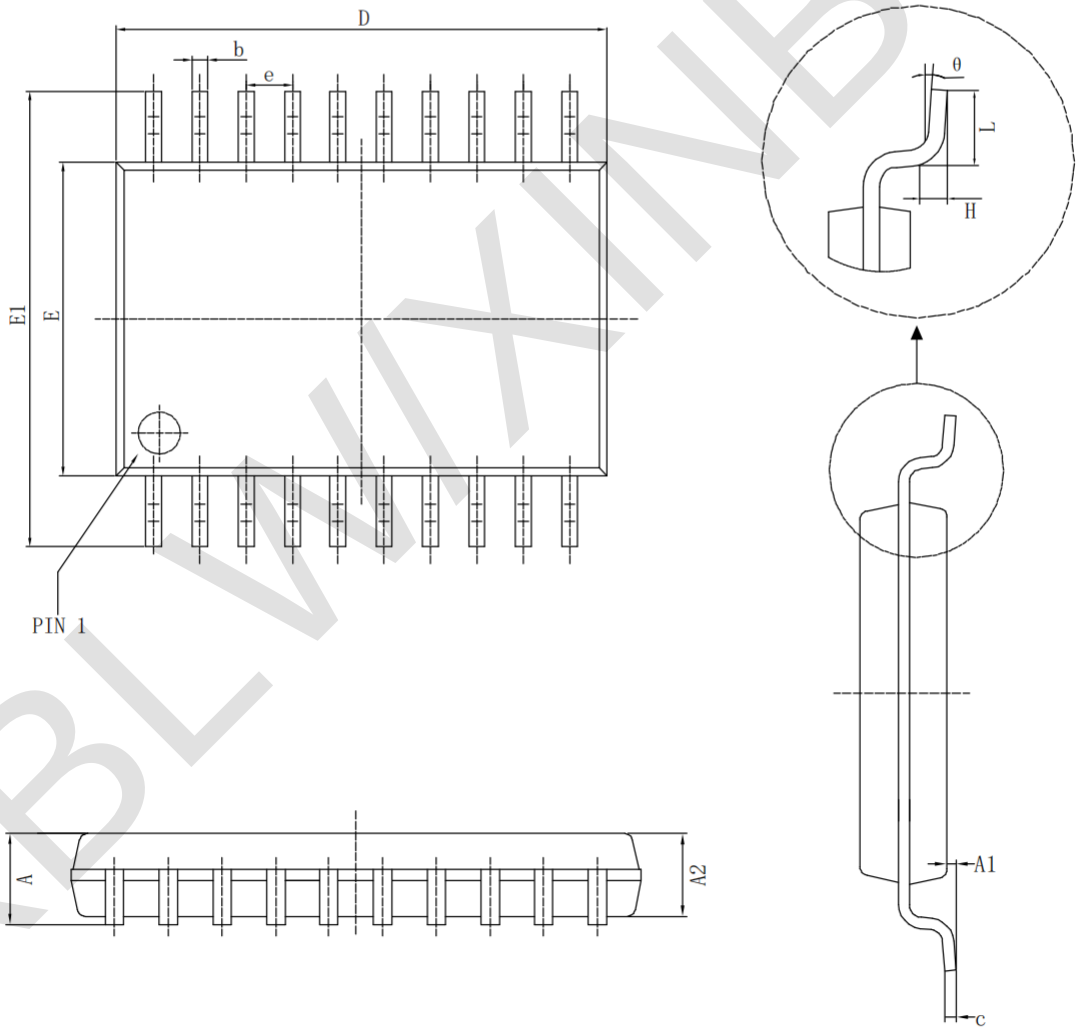
· SOP-20

Size / Symbol	Dimensions In Millimeters		Size / Symbol	Dimensions In Inches	
	Min(mm)	Max(mm)		Min(in)	Max(in)
A	2.470	2.650	A	0.097	0.104
A1	0.050	0.300	A1	0.002	0.012
A2	2.200	2.440	A2	0.087	0.096
b	0.350	0.500	b	0.014	0.020
c	0.150	0.300	c	0.006	0.012
D	12.54	12.94	D	0.494	0.509
E	10.00	10.60	E	0.394	0.417
E1	7.300	7.700	E1	0.287	0.303
e	1.270(BSC)		e	0.050(BSC)	
L	0.400	1.050	L	0.016	0.041
L1	1.300	1.500	L1	0.051	0.059
θ	0°	8°	θ	0°	8°



· TSSOP-20

Size / Symbol	Dimensions In Millimeters		Size / Symbol	Dimensions In Inches	
	Min(mm)	Max(mm)		Min(in)	Max(in)
D	6.400	6.600	D	0.252	0.259
E	4.300	4.500	E	0.169	0.177
b	0.190	0.300	b	0.007	0.012
c	0.090	0.200	c	0.004	0.008
E1	6.250	6.550	E1	0.246	0.258
A		1.200	A		0.047
A2	0.800	1.000	A2	0.031	0.039
A1	0.050	0.150	A1	0.002	0.006
e	0.65(BSC)		e	0.026(BSC)	
L	0.500	0.700	L	0.020	0.028
H	0.25(TYP)		H	0.01(TYP)	
θ	1°	7°	θ	1°	7°



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